



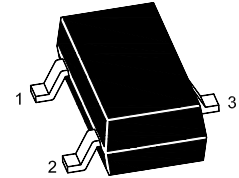
MMBTRC116SS~MMBTRC122SS

NPN Digital Transistor

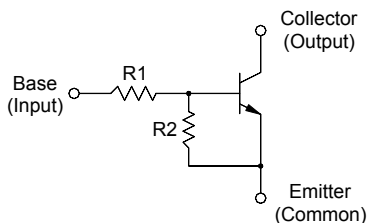
Features

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process

SOT-23
(TO-236)



1.Base 2.Emitter 3.Collector



Resistor Values

Type	R1 (K Ω)	R2 (K Ω)	Marking
MMBTRC116SS	1	10	16BR
MMBTRC117SS	2.2	2.2	17BR
MMBTRC118SS	2.2	10	18BR
MMBTRC119SS	4.7	10	19BR
MMBTRC120SS	10	4.7	20BR
MMBTRC121SS	47	10	21BR
MMBTRC122SS	100	100	22BR

Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

Parameter	Symbol	Value	Unit	
Output Voltage	V_o	50	V	
Input Voltage	V_i	MMBTRC116SS	10, - 5	V
		MMBTRC117SS	12, - 10	
		MMBTRC118SS	12, - 5	
		MMBTRC119SS	20, - 7	
		MMBTRC120SS	30, - 10	
		MMBTRC121SS	40, - 15	
		MMBTRC122SS	40, - 10	
Output Current	I_o	100	mA	
Total Power Dissipation	P_{tot}	200	mW	
Junction Temperature	T_j	150	$^\circ\text{C}$	
Storage Temperature Range	T_{Stg}	- 55 to + 150	$^\circ\text{C}$	



MMBTRC116SS~MMBTRC122SS

NPN Digital Transistor

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_O = 5\text{ V}$, $I_O = 5\text{ mA}$	MMBTRC116SS	33	-	-	-
at $V_O = 5\text{ V}$, $I_O = 20\text{ mA}$	MMBTRC117SS	20	-	-	-
at $V_O = 5\text{ V}$, $I_O = 10\text{ mA}$	MMBTRC118SS	33	-	-	-
at $V_O = 5\text{ V}$, $I_O = 10\text{ mA}$	MMBTRC119SS	30	-	-	-
at $V_O = 5\text{ V}$, $I_O = 10\text{ mA}$	MMBTRC120SS	24	-	-	-
at $V_O = 5\text{ V}$, $I_O = 5\text{ mA}$	MMBTRC121SS	33	-	-	-
at $V_O = 5\text{ V}$, $I_O = 5\text{ mA}$	MMBTRC122SS	62	-	-	-
Output Cutoff Current at $V_O = 50\text{ V}$	$I_{O(OFF)}$	-	-	500	nA
Input Current at $V_I = 5\text{ V}$	MMBTRC116SS MMBTRC117SS MMBTRC118SS MMBTRC119SS MMBTRC120SS MMBTRC121SS MMBTRC122SS	- - - - - - -	- - - - - - -	7.2 3.8 3.8 1.8 0.88 0.16 0.15	mA
Output Voltage at $I_O = 10\text{ mA}$, $I_I = 0.5\text{ mA}$	MMBTRC116SS MMBTRC117SS MMBTRC118SS MMBTRC119SS MMBTRC120SS MMBTRC121SS MMBTRC122SS	- - - - - - -	- - - - - - -	0.3 0.3 0.3 0.3 0.3 0.3 0.3	V
Input Voltage (ON) at $V_O = 0.3\text{ V}$, $I_O = 20\text{ mA}$	MMBTRC116SS MMBTRC117SS MMBTRC118SS MMBTRC119SS MMBTRC120SS MMBTRC121SS MMBTRC122SS	- - - - - - -	- - - - - - -	3 3 3 2.5 3 5 3	V
Input Voltage (OFF) at $V_{CC} = 5\text{ V}$, $I_O = 100\text{ }\mu\text{A}$	MMBTRC116SS MMBTRC117SS MMBTRC118SS MMBTRC119SS MMBTRC120SS MMBTRC121SS MMBTRC122SS	0.3 0.5 0.3 0.3 0.8 1 0.5	- - - - - - -	- - - - - - -	V
Transition Frequency at $V_O = 10\text{ V}$, $I_O = 5\text{ mA}$	$f_T^{1)}$	-	250	-	MHz

¹⁾ Characteristic of transistor only.

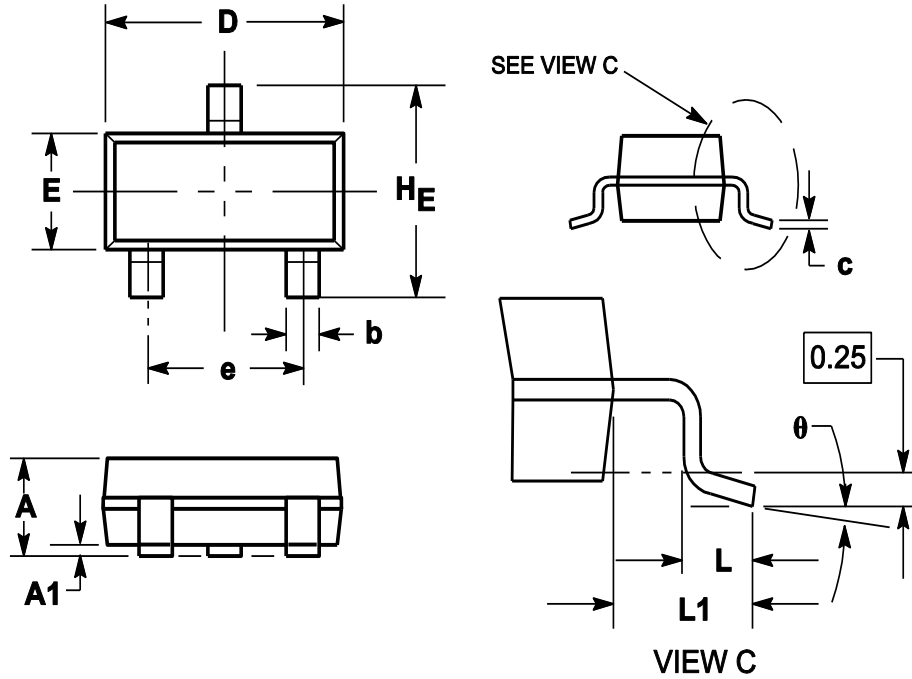


MMBTRC116SS~MMBTRC122SS NPN Digital Transistor

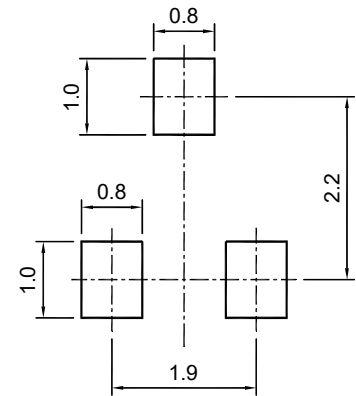
Package Outline

SOT-23 (TO-236)

Dimensions in mm



Symbol	Dimensions in millimeter		
	Min.	Typ.	Max.
A	0.900	1.025	1.150
A1	0.000	0.050	0.100
b	0.300	0.400	0.500
c	0.080	0.115	0.150
D	2.800	2.900	3.000
E	1.200	1.300	1.400
HE	2.250	2.400	2.550
e	1.800	1.900	2.000
L1	0.550REF		
L	0.300		0.500
θ	0°		8°



SOT-23 (TO-236)

Recommended soldering pad